




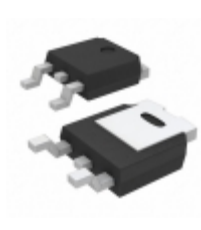





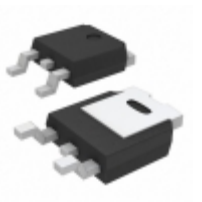
 life.augmented	Hersteller-Teilenummer: STD9NM60N
	Hersteller / Marke: STMicroelectronics
	Teil der Beschreibung: MOSFET N-CH 600V 6.5A DPAK
	Datenblätter:  STD9NM60N.pdf
RoHs Status: Bleifrei / RoHS-konform	Lagerzustand: New original, 52536 pcs Stock Available.
Lieferung von: Hong Kong	Versandweg: DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.	

Spezifikationen

Teilenummer	STD9NM60N
Hersteller	STMicroelectronics
Beschreibung	MOSFET N-CH 600V 6.5A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	52536 pcs Stock
Serie	MDmesh™ II
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	150 °C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	70W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	6.5A (Tc)
Rds On (Max) @ Id, Vgs	745 mOhm @ 3.25A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	17.4nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	452pF @ 50V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tape & Reel (TR)



















































STD9NM60N ist neu im Original, Suche STD9NM60N Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie STD9NM60N STMicroelectronics mit Garantie und Vertrauen.
Anfrage STD9NM60N: Info@Y-IC.com

Sie können auch interessiert sein:

 STDC1150XXBCEA3 CONEXANT STDC1150XXBCEA3 CONEXANT	 STD9N65M2 STMicroelectronics MOSFET N-CH 650V 5A DPAK	 STDC1100 CONEXANT STDC1100 CONEXANT	 STDC2150 SIGEATE STDC2150 SIGEATE
 STD9NM40N STMicroelectronics MOSFET N-CH 400V 5.6A DPAK	 STD9N80K5 STMicroelectronics MOSFET N-CHANNEL 800V 7A DPAK	 STD9NM60N-1 ST STD9NM60N-1 ST	 STD9NM50N STMicroelectronics MOSFET N-CH 500V 7.5A DPAK

heiße Teile

Mehr

 STD90NH02	 STD90NH02-1	 STD90NH02L	 STD90NH02LT4	 STD90NH02LT4-E
 STD90NS3LLH7	 STD93003	 STD95N04	 STD95N2LH5	 STD95N3LL
 STD95N3LLH6	 STD95N3LLH6-H	 STD95N4F3	 STD95N4LF3	 STD95NF04
 STD95NH02L	 STD95NH02L-1	 STD95NH02LT4	 STD96N3LLH6	 STD9807S5-TRG
 STD9N10L	 STD9N10T4	 STD9N60M2	 STD9NM40N	 STD9NM50N
 STD9NM60N-1	 STDC1100	 STDC1150XXBCEA3	 STDC2150	 STDC3000XXBLEB1
 STDC7100XXBCEA1	 STDO57/08	 STDP2600	 STDP2600-AC	 STDP2600-ACT
 STDP2650-ADT	 STDP3100-AB/SS	 STDP4010-AC	 STDP4020-AB	 STDP4020-AD
 STDP4328-BA	 STDP5300-AC	 STDP6018	 STDP6036	 STDP6038-AC
 STDS160H160TV	 STDTR813BJR	 STDVE001ABTR	 STDVE003ABTR	 STDVE103ABTY

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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